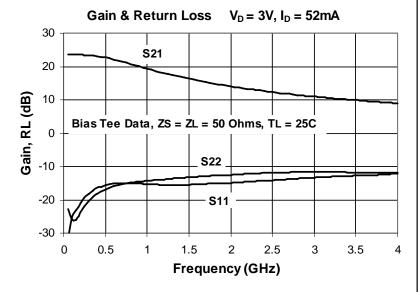


### **Product Description**

Sirenza Microdevices SGC-4486Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with a patented active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 3V supply, the SGC-4486Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SGC-4486Z is designed for high linearity 3V gain block applications that require small size and minimal external components. It is internally matched to 50 ohms.



# SGC-4486Z

# 50-4000 MHz Active Bias Silicon Germanium Cascadable Gain Block





#### **Product Features**

- Single Fixed 3V Supply
- No Dropping Resistor Required
- Patented Self-Bias Circuitry
- P1dB = 12.7 dBm at 1950 MHz
- OIP3 = 27.5 dBm at 1950 MHz
- Robust 1000V ESD, Class 1C HBM

## **Applications**

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS, WCDMA
- IF Amplifier
- Wireless Data, Satellite

Symbol	Parameters	Units	Frequency	Min.	Тур.	Max.
			850 MHz	19.0	20.5	22.0
G	Small Signal Gain	dB	1950 MHz	13.0	14.5	16.0
			2400 MHz		12.3	
P <sub>1dB</sub>			850 MHz		13.8	
	Output Power at 1dB Compression	dBm	1950 MHz	11.7	12.7	
			2400 MHz		12.4	
			850 MHz		29.0	
OIP <sub>3</sub>	Output Third Order Intercept Point	dBm	1950 MHz	25.5	27.5	
			2400 MHz		26.5	
IRL	Input Return Loss	dB	1950 MHz	10.5	14.5	
ORL	Output Return Loss	dB	1950 MHz	7.5	11.5	
NF	Noise Figure	dB	1930 MHz		3.4	4.4
$V_D$	Device Operating Voltage	V			3	
I <sub>D</sub>	Device Operating Current	mA		46	52	58
Rth, j-l	Thermal Resistance (junction to lead)	°C/W			145	

Test Conditions: $V_D = 3.0V$  $I_D = 52mA$  $T_L = 25^{\circ}C$ OIP $_3$  Tone Spacing = 1MHzBias Tee Data $Z_S = Z_L = 50$  OhmsPout per tone = -5 dBm

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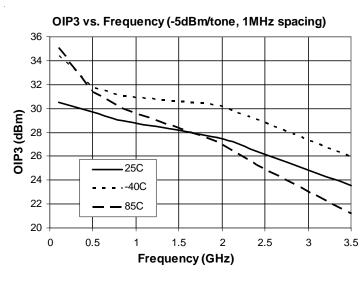
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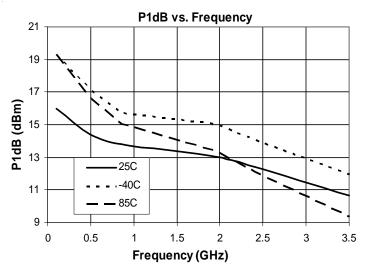


Typical RF Performance at Key Operating Frequencies (Bias Tee)								
Symbol	Parameter		Frequency (MHz)					
	Symbol	raiametei	Unit	100	500	850	1950	2400
G	Small Signal Gain	dB	23.5	22.5	20.5	14.5	12.3	9.5
OIP <sub>3</sub>	Output Third Order Intercept Point	dBm	30.5	29.5	29.0	27.5	26.5	23.5
P <sub>1dB</sub>	Output Power at 1dB Compression		16.1	14.4	13.8	12.7	12.4	10.6
IRL	Input Return Loss	dB	24.0	15.5	16.5	14.5	14.5	13.0
ORL	Output Return Loss	dB	25.0	17.0	16.5	11.5	12.0	11.0
S <sub>12</sub>	Reverse Isolation	dB	25.0	26.0	25.0	20.5	19.0	17.5
NF	Noise Figure	dB	2.8	2.8	3.1	3.4	3.9	4.8

**Test Conditions:**  $V_D = 3V$   $I_D = 52mA$   $OIP_3$  Tone Spacing = 1MHz, Pout per tone = -5 dBm  $T_L = 25^{\circ}C$   $Z_S = Z_L = 50$  Ohms

Typical Performance with Bias Tee,  $V_D = 3V$ ,  $I_D = 52mA$ 





Absolute Maximum Ratings				
Parameter	Absolute Limit			
Max Device Current (I <sub>CE</sub> )	110 mA			
Max Device Voltage (V <sub>CE</sub> )	4.5 V			
Max. RF Input Power* (See Note)	+18 dBm			
Max. Junction Temp. (T <sub>J</sub> )	+150°C			
Operating Temp. Range (T <sub>L</sub> )	-40°C to +85°C			
Max. Storage Temp.	+150°C			

\*Note: Load condition,  $Z_L = 50$  Ohms

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:  $I_DV_D < (T_J - T_L) / R_{TH}$ , j-l  $T_L = T_{LEAD}$ 

Reliability & Qualification information				
Parameter	Rating			
ESD Rating - Human Body Model (HBM)	Class 1C			
Moisture Sensitivity Level	MSL 1			

This product qualification report can be downloaded at www.sirenza.com



### Caution: ESD sensitive

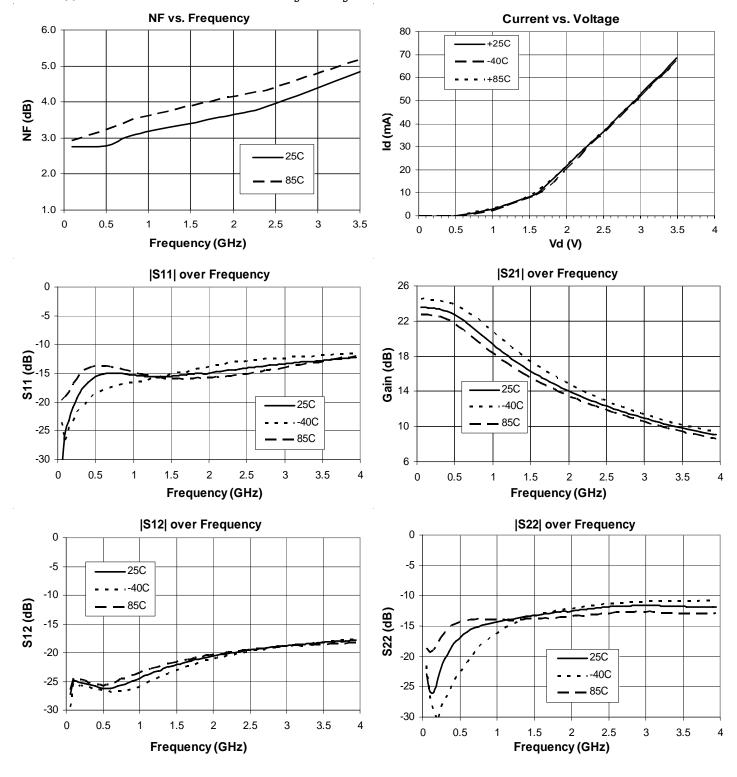
Appropriate precautions in handling, packaging and testing devices must be observed.

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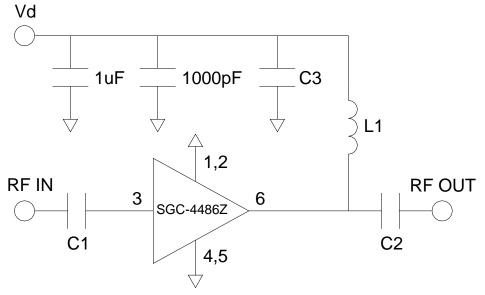
Phone: (800) SMI-MMIC 2



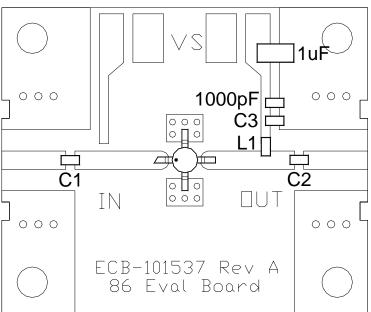
# Typical Performance with Bias Tee, $V_D = 3V$ , $I_D = 52mA$



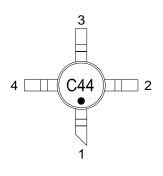




Application Circuit Element Values					
Reference Designator	100-2000MHz	2000-4000MHz			
C1	1000pF	2.7pF			
C2	100pF	6.8pF			
C3	100pF	6.8pF			
L1	120nH	39nH			



### **Part Identification Marking & Pinout**

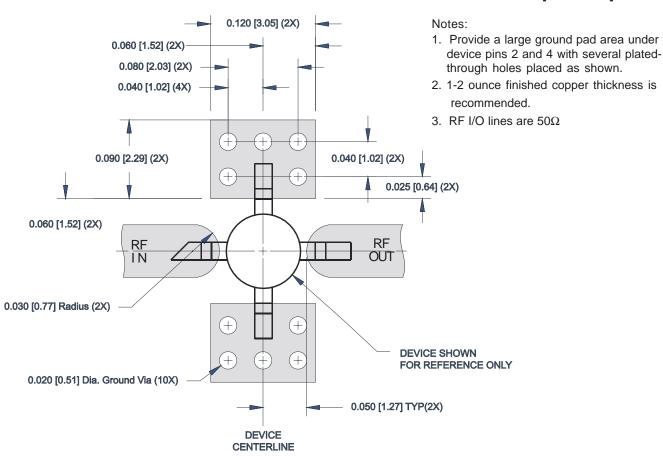


Pin#	Function	Description	Part / Evaluation Board Ordering Information			
1		RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation	Part Number	Description	Reel Size	Devices / Reel
2,4		Connection to ground. Use via holes as close to the device ground leads as possible to reduce ground inductance and	SGC-4486Z	Lead Free, RoHs Compliant	13"	3000
		achieve optimum RF performance	SGC-4486Z-EVB1	100-2000 MHz Evaluation Board	N/A	N/A
	RF OUT /	RF OUT / RF output and bias pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of	SGC-4486Z-EVB2	2000-4000 MHz Evaluation Board	N/A	N/A
		operation.			•	



### **86 PCB Pad Layout**

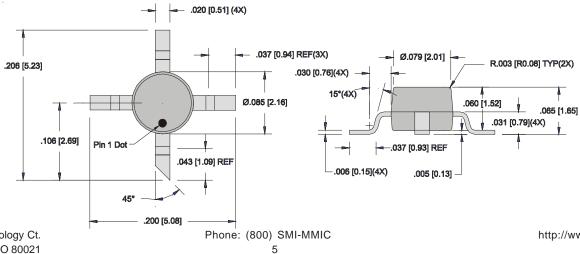
### Dimensions in inches [millimeters]



### **86 Nominal Package Dimensions**

Dimensions in inches [millimeters]

A link to the 86 package outline drawing with full dimensions and tolerances may be found on the product web page at www.sirenza.com.



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http://www.sirenza.com